

Product data sheet

Product profile

1.1 General description

The BB181LX is a planar technology variable capacitance diode in a SOD882T ultra small leadless plastic SMD package.

1.2 Features

- Excellent linearity
- Ultra small leadless SMD package
- C_{d(28V)}: 1 pF; ratio: 14

1.3 Applications

- Voltage Controlled Oscillators (VCO)
- Electronic tuning in satellite tuners
- Tunable coupling

Pinning information 2.

Table 1. **Pinning**

Pin	Description	Simplified outline	Graphic symbol
1	cathode	[1]	٦L
2	anode	1 2	sym008
		Transparent top view	

^[1] The marking bar indicates the cathode.

3. **Ordering information**

Table 2. **Ordering information**

Type number	Package			
	Name	Description	Version	
BB181LX	-	leadless ultra small plastic package; 2 terminals; body 1 \times 0.6 \times 0.4 mm	SOD882T	





VHF variable capacitance diode

Marking 4.

Table 3. **Marking codes**

Type number	Marking code
BB181LX	L6

Limiting values 5.

Table 4. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{R}	reverse voltage		-	32	V
I _F	forward current		-	20	mA
T _{stg}	storage temperature		-55	+150	°C
Tj	junction temperature		-55	+125	°C

Characteristics 6.

Table 5. Characteristics

$I_{R} \qquad \text{reverse current} \qquad \underbrace{\begin{array}{c} \text{see } \underline{\text{Figure 3}}}_{V_{R} = 30 \text{V}} \qquad - \qquad - \qquad 10 \qquad \text{n.} \\ V_{R} = 30 \text{V}; T_{j} = 85 ^{\circ}\text{C} \qquad - \qquad - \qquad 200 \text{n.} \\ V_{R} = 30 \text{V}; T_{j} = 85 ^{\circ}\text{C} \qquad - \qquad - \qquad 200 \text{n.} \\ V_{R} = 30 \text{V}; T_{j} = 85 ^{\circ}\text{C} \qquad - \qquad - \qquad 200 \text{n.} \\ V_{R} = 0.5 \text{V} \qquad \text{See } \underline{\text{Figure 1}} \text{and} \\ \underline{\text{Figure 4}} \qquad \qquad$	Table 6.	naraotoriotioo					
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	I _R	reverse current	see Figure 3				
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$			V _R = 30 V	-	-	10	nA
$See \ \frac{\text{Figure 2}}{\text{C}_{d}} \qquad \qquad \frac{\text{diode capacitance}}{\text{diode capacitance}} \qquad \frac{\text{f = 1 MHz; see } \underline{\text{Figure 1}}}{\text{Figure 4}} \text{ and} \\ \qquad \qquad \frac{\text{Figure 4}}{\text{V}_{R} = 0.5 \text{ V}} \qquad \qquad 8 \qquad - \qquad 17 \qquad \text{pl} \\ \qquad \qquad \qquad \text{V}_{R} = 28 \text{ V} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \qquad \qquad \text{Proposition 1}} \qquad \qquad \frac{\text{Figure 2}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \qquad \qquad \frac{\text{Figure 2}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \qquad \qquad \frac{\text{Figure 4}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \qquad \frac{\text{Figure 4}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \qquad \frac{\text{Figure 4}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \qquad \frac{\text{Figure 4}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \qquad \frac{\text{Figure 4}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \frac{\text{Figure 4}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \frac{\text{Figure 4}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \frac{\text{Figure 4}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \frac{\text{Figure 4}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \frac{\text{Figure 4}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \frac{\text{Figure 4}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \frac{\text{Figure 4}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \frac{\text{Figure 4}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \frac{\text{Figure 5}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \frac{\text{Figure 6}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \frac{\text{Figure 6}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \frac{\text{Figure 6}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \frac{\text{Figure 6}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \frac{\text{Figure 6}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \frac{\text{Figure 6}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \frac{\text{Figure 6}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \frac{\text{Figure 6}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \frac{\text{Figure 6}}{\text{V}_{R} = 28 \text{ V}} \qquad \qquad 0.7 \qquad - \qquad 1.055 \text{pl} \\ \qquad \frac{\text{Figure 6}}{\text{V}_{R} = 28 $			$V_R = 30 \text{ V}; T_j = 85 ^{\circ}\text{C}$	-	-	200	nA
Figure 4 $V_R = 0.5 \text{ V}$ $V_R = 28 \text{ V}$ $0.7 - 1.055 \text{ p}$	r _s	diode series resistance	- • ·	-	2.0	-	Ω
V _R = 28 V 0.7 - 1.055 pt	C_d	diode capacitance					
			$V_R = 0.5 V$	8	-	17	pF
$C_{d(0V5)}/C_{d(28V)}$ diode capacitance ratio (0.5 V to 28 V) f = 1 MHz 12 - 16			V _R = 28 V	0.7	-	1.055	pF
	C _{d(0V5)} /C _{d(28V}	diode capacitance ratio (0.5 V to 28 V) f = 1 MHz	12	-	16	

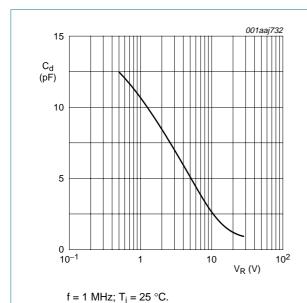


Fig 1. Diode capacitance as a function of reverse voltage; typical values

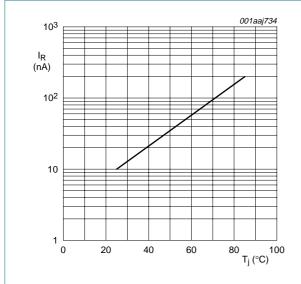


Fig 3. Reverse current as a function of junction temperature; maximum values

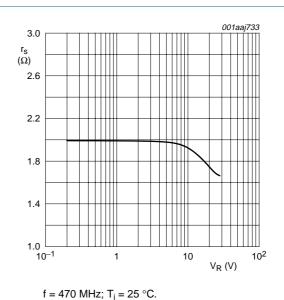
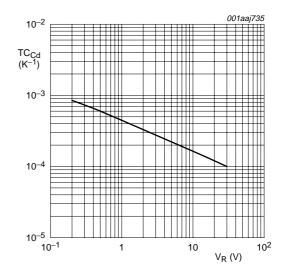


Fig 2. Diode serial resistance as a function of reverse voltage; typical values



 $T_i = 0$ °C to 85 °C.

Fig 4. Temperature coefficient of diode capacitance as a function of reverse voltage; typical values

7. Package outline

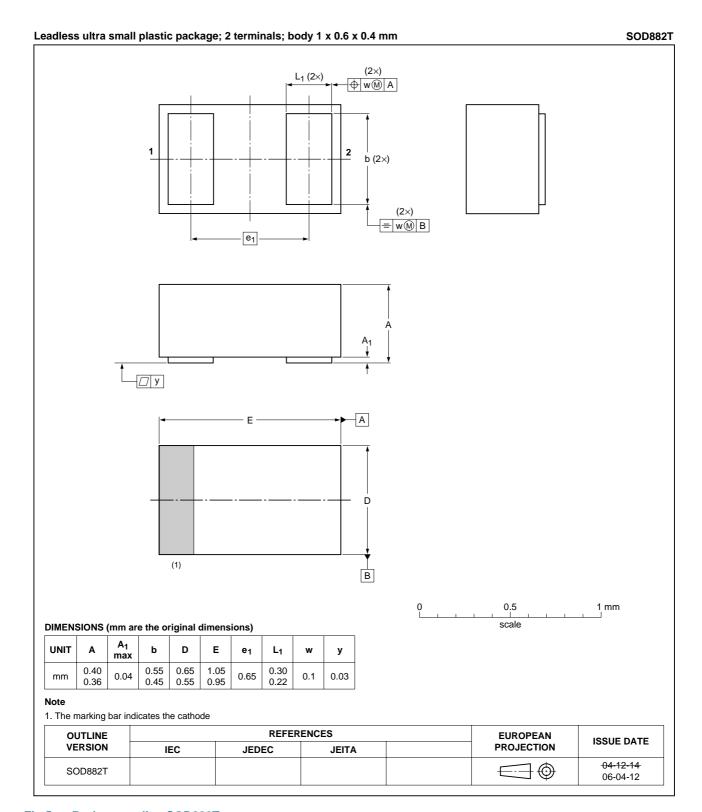


Fig 5. Package outline SOD882T



VHF variable capacitance diode

8. Abbreviations

Table 6. Abbreviations

Acronym	Description
SMD	Surface Mounted Device
VHF	Very High Frequency

9. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BB181LX_1	20090219	Product data sheet	-	-

VHF variable capacitance diode

10. Legal information

10.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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BB181LX NXP Semiconductors

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Website:

Welcome to visit www.ameya360.com

Contact Us:

Address:

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd Minhang District, Shanghai , China

Sales:

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

Customer Service :

Email service@ameya360.com

Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com